

A Tracker for the Mu3e Experiment based on High Voltage Monolithic Active Pixel Sensors

D. Wiedner¹, S. Bachmann¹, N. Berger¹, M. Kiehn¹, I. Peric², A.-K. Perrevoort¹, A. Schöning¹

1) Physics Institute, Heidelberg University, INF 226, 69120 Heidelberg, Germany 2) Institute for Computer Engineering (ZITI), Heidelberg University, 68131 Mannheim, Germany

Abstract:

The proposed Mu3e experiment will study the lepton flavor violating decay μ —eee which is strongly (10⁻⁵⁰) suppressed in the standard model, but enhanced to observable levels in many models for new physics. In order to achieve the proposed branching ratio

sensitivity of 10⁻¹⁶ the detector has to have a high rate capability and a good background suppression, which in turn requires excellent momentum and vertex resolution. The Mu3e detector consists of two double layers of high voltage monolithic active pixel sensors (HV-MAPS) around a target double cone. To minimize

multiple scattering of the low energetic decay electrons (< 53 MeV), an ultra-light design is proposed, using HV-MAPS thinned to \leq 50 μ m. With on-sensor pre-amplification, discrimination and zero-suppression, a separate read-out chip can be omitted, which further reduces the material budget.

Theory:

In the Standard Model (SM) of elementary particle physics, the decay $\mu\to eee$ can occur via lepton mixing. It is however suppressed to an unobservable low branching fraction of O(10⁻⁵⁰). Any observation of $\mu\to eee$ would be a clear signal for new physics, and many models predict enhanced lepton flavor violation, e.g. super-symmetry, grand unified models, left-right symmetric models, models with an extended Higgs sector, large extra dimensions etc. LFV can proceed either via loops or at tree level. Introducing a common scale Λ and a relative strength κ between the dipole term and the 4-fermion contact interaction gives a simplified Lagrangian:

$$L_{LFV} = \frac{m_{\mu}}{(\kappa+1)\Lambda^{2}} A_{R} \bar{\mu}_{R} \sigma^{\mu\nu} e_{L} F_{\mu\nu} + \frac{\kappa}{(\kappa+1)\Lambda^{2}} (\bar{\mu}_{L} \gamma^{\mu} e_{L}) (\bar{e}_{L} \gamma^{\mu} e_{L})$$

$$\downarrow 0^{-2} \quad 10^{-1} \quad 1 \quad 10 \quad 10^{2} \quad 10^{3} \quad 10^{4}$$

$$\downarrow 0^{-2} \quad 10^{4} \quad \mu \rightarrow \text{eee}$$

$$\downarrow 0^{-3} \quad 10^{-16}$$

$$\downarrow 0^{-4} \quad \mu \rightarrow \text{eee}$$

$$\downarrow 0^{-3} \quad 10^{-16}$$

$$\downarrow 0^{-4} \quad \mu \rightarrow \text{eee}$$

$$\downarrow 0^{-4} \quad 10^{-16}$$

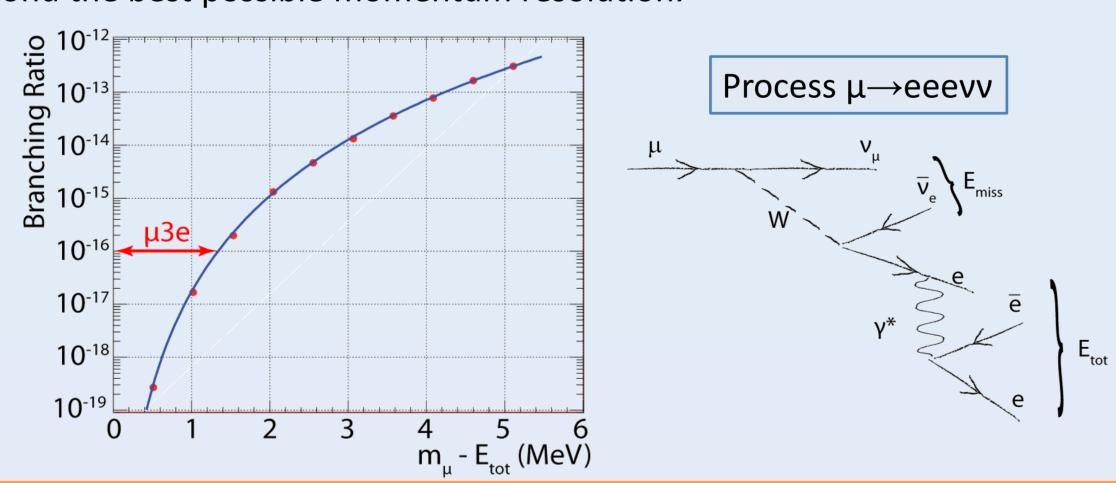
$$\downarrow 0^{-4} \quad 10^{-4} \quad 10^{-4}$$

$$\downarrow 0^{-4} \quad 10^{-4} \quad 10^{-4} \quad 10^{-4} \quad 10^{-4}$$

$$\downarrow 0^{-4} \quad 10^{-4} \quad 10^{-4} \quad 10^{-4} \quad 10^{-4} \quad 10^{-4} \quad 10^{-4}$$

$$\downarrow 0^{-4} \quad 10^{-4} \quad 10^{-4$$

The main sources of background are accidental coincidences of tracks from Michel decays with electron-positron pairs from Bhabha scattering, photon conversion etc. and the radiative decay with internal conversion μ —eeevv (BR 3.4 × 10⁻⁵). The first requires excellent vertex and timing resolution, the second the best possible momentum resolution.



Muon beam at PSI:

Paul Scherrer Institute Switzerland:

- 2.2 mA of 590 MeV/c protons
- Future: up to 3 mA (1.8 MW)
- Phase I:
 - Surface muons from target E
 - Up to a few $10^8 \,\mu/s$
- Phase II:
 - New beam line at the neutron source
 - Several 10⁹ μ/s possible

Accelerator Facilities C Cockert/Walton Ream Transport Lines Previous Coulomb Readon-Readon P2 E gar Transport Lines Readon-Readon Readon Readon-Readon Readon-Readon Readon Readon-Readon Readon-Readon-Readon Readon-Readon-Readon Readon-Readon-Readon Readon-Readon-Readon Readon-Readon-Readon-Readon-Readon-Readon-Readon-

Outlook:

2012 Letter of intent to PSI, Tracker prototype, technical design

2013 Technical design report, detector construction

2014 Installation and commissioning at PSI

2015 Data taking at up to a few $10^8 \mu/s$

2016+ Construction of new beam-line at PSI

2017++ Data taking at up to $3.10^9 \,\mu/s$

Challenges:

- High rates
- Excellent momentum resolution
- Good vertex resolution
- Good timing resolution
- Extremely low material budget

Tracking:

Use central part of the detector for track finding, vertexing and timing. The best resolution in presence of multiple scattering is obtained from tracks curling half turns in the B ~ 1 T field.

Momentum resolutions
< 0.3 MeV/c are possible over

Momentum resolutions
< 0.3 MeV/c are possible over
a wide kinematic range,
making a three track mass
resolution of ~ 0.5 MeV/c² possible.

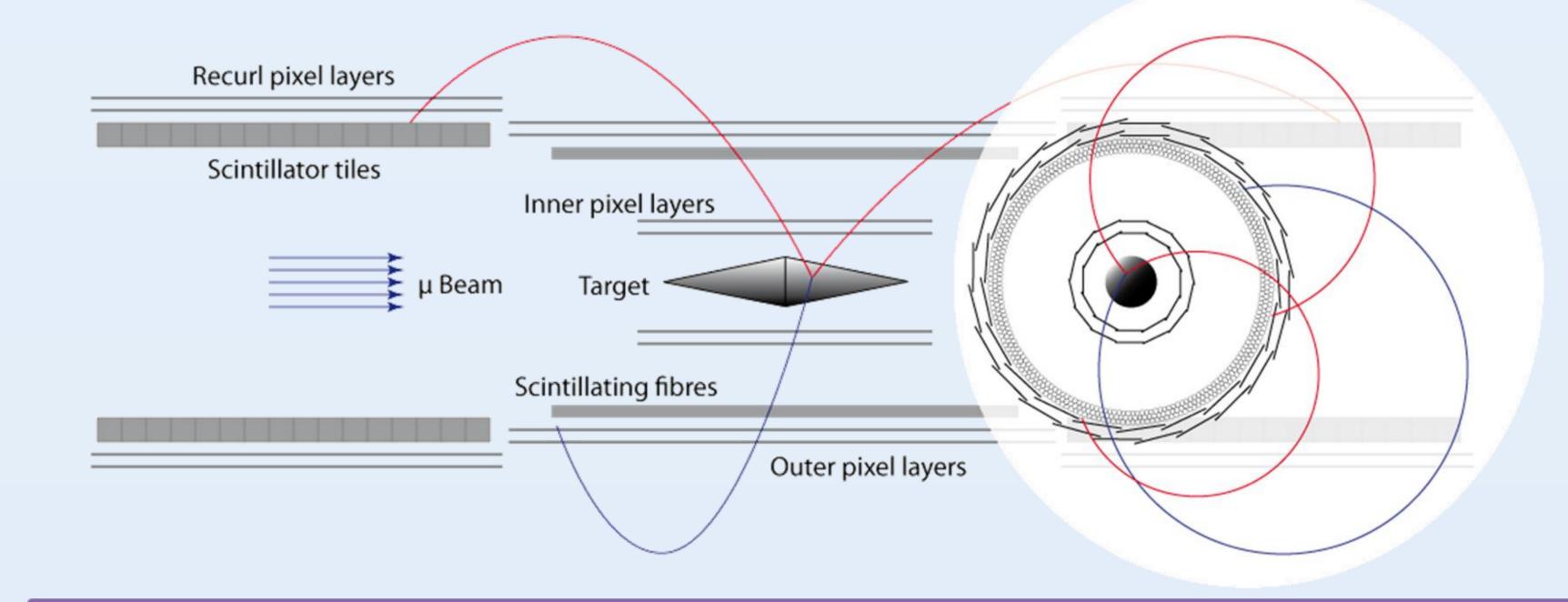
Momentum resolution (MeV/c)

(Multiple scattering only)

1.5 1.25 1

0.75 0.5 0.25

0.25 0.25 9



Detector Concept:

Long Tube Design:

For a high acceptance of recurling particles, the detector needs to be long (> 1 m). However, only the central ~ 25 cm needs to be thin, simplifying mechanics and allowing for precise timing in thick scintillator tiles.

Target:

Double cone target made from 70 µm Aluminum – large area for good vertex separation.

Mechanics:

Sensors supported on 25 µm Kapton™ strips with signal and power traces printed in Aluminum – extremely light and surprisingly sturdy.

Timing:

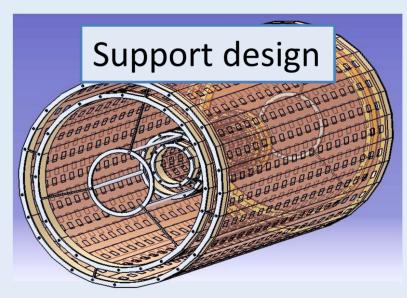
250 μ m scintillating fibers in the central region for first timing measurement. Precise timing from ~ 1 cm thick scintillating tiles in the recurl tubes

Pixel Sensor:

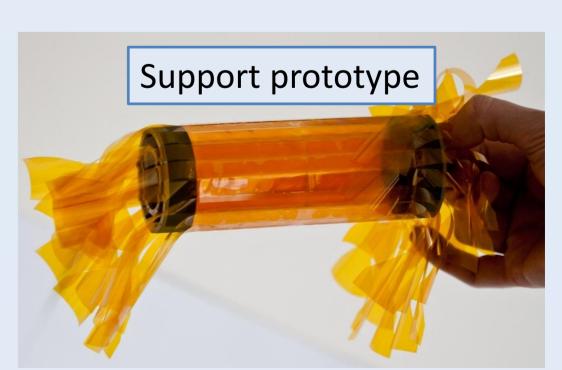
- 80 x 80 μ m² pixels sensors cut to 2 × 6 or 1 × 6 cm²
- Thinned to ≤ 50 μm
- \rightarrow thickness of 4 pixel layers ~ 2 ‰ X₀
- Total ~ 200 Million pixels
- Cooled by helium atmosphere
- Maximum readout frequency ~ 20 MHz
- Binary readout

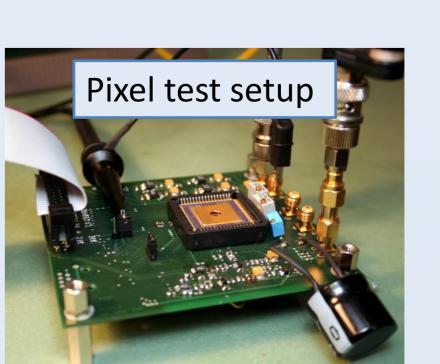
Readout:

- Triggerless readout with ~ 100 Gbyte/s to an online farm.
- Fast track finding and reconstruction on GPUs (> 10⁹ tracks/s).
- Reduction to ~ 100 Mbyte/s for online storage and analysis.

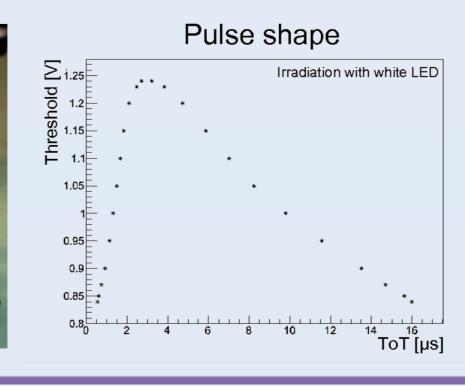








P-substrate



HV-MAPS:

Using a commercial 180 nm CMOS process originating in the automotive industry, high voltage monolithic active pixel sensors housing the pixel electronics inside a deep N-well can be implemented. The high voltage ($\sim 50 \text{ V}$) leads to a small depletion zone with fast charge collection. Most of the substrate is passive and the wafer can be thinned to $< 50 \mu m$.

Ref.: I. Peric, A novel monolithic pixelated particle detector implemented in high-voltage CMOS technology Nucl.Instrum.Meth., 2007, A582, 876

N-well

E field